

# SHANGHAI SUNRISE ELECTRONICS CO., LTD.

## **DF005S THRU DF10S**

SINGLE PHASE GLASS PASSIVATED SURFACE MOUNT **BRIDGE RECTIFIER** 

**TECHNICAL SPECIFICATION** 

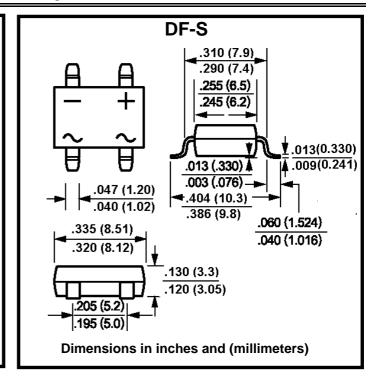
VOLTAGE: 50 TO 1000V CURRENT: 1.0A

#### **FEATURES**

- For surface mount application
- Reliable low cost construction utilizing molded plastic technique
- Surge overload rating: 50 A peak
- High temperature soldering guaranteed: 250°C/10sec/ at terminals

#### **MECHANICAL DATA**

- Terminal: Plated leads solderable per MIL-STD 202E, method 208C
- Case: UL-94 Class V-O recognized flame retardant epoxy
- Polarity: Polarity symbol marked on body
- Mounting position: Any



### MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

(Single-phase, half-wave, 60Hz, resistive or inductive load rating at 25°C, unless otherwise stated, for capacitive load, derate current by 20%)

RATINGS	SYMBOL	DF 005S	DF 01S	DF 02S	DF 04S	DF 06S	DF 08S	DF 10S	UNITS
Maximum Repetitive Peak Reverse Voltage	$V_{RRM}$	50	100	200	400	600	800	1000	V
Maximum RMS Voltage	$V_{RMS}$	35	70	140	280	420	560	700	V
Maximum DC Blocking Voltage	$V_{DC}$	50	100	200	400	600	800	1000	V
Maximum Average Forward Rectified Currel	nt ,	1.0							А
$(T_a=40^{\circ}C)$	I <sub>F(AV)</sub>								
Peak Forward Surge Current (8.3ms single	I	50							Α
half sine-wave superimposed on rated load)	I <sub>FSM</sub>								
Maximum Instantaneous Forward Voltage	$V_{F}$	1.1							V
(at forward current 1.0A)	<b>v</b> F								
Maximum DC Reverse Current T <sub>a</sub> =25	°C ,	10.0							μΑ
(at rated DC blocking voltage) T <sub>a</sub> =125	l ln	500							μΑ
Typical Junction Capacitance (Note	1) C <sub>J</sub>	C <sub>J</sub> 25							pF
Storage and Operating Junction Temperature	e T <sub>STG</sub> ,T <sub>J</sub>	-55 to +150						°C	
Note:									

1. Measured at 1.0 MHz and applied voltage of  $4.0V_{\rm dc}$